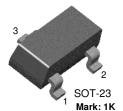


SEMICONDUCTOR®

MMBT6428

NPN General Purpose Amplifier

- This device designed for general pupose amplifier applications at collector currents to 300mA
- Sourced from process 10.



1. Base 2. Emitter 3. Collector

Absolute Maximum Ratings* T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	50	V
V _{CBO}	Collector-Base Voltage	60	V
I _C	Collector Current - Continuous	500	mA
T _J , T _{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

Electrical Characteristics T_C=25°C unless otherwise noted

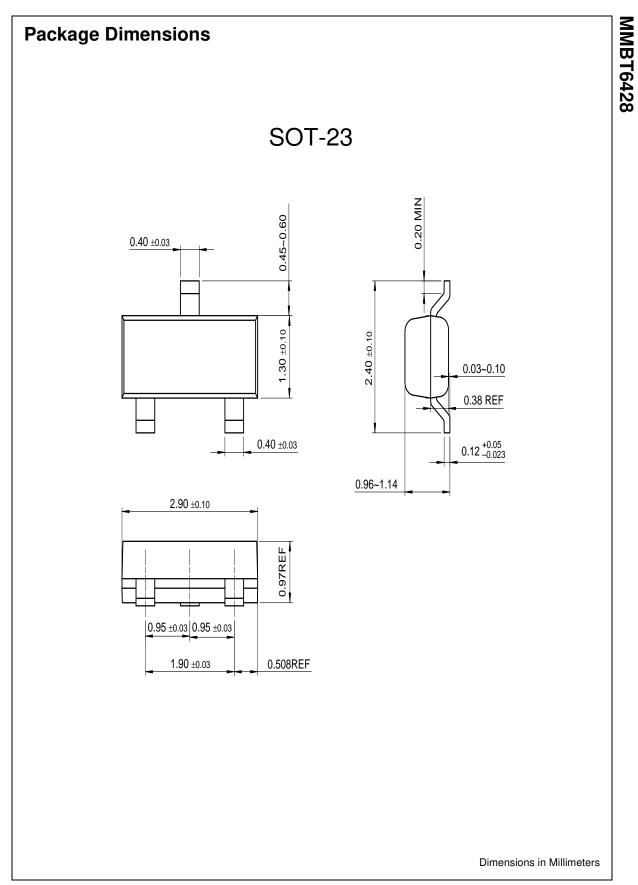
Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Characte	eristics	-	•		
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_{\rm C} = 1.0 {\rm mA}, I_{\rm B} = 0$ 50			V
V _{(BR)CBO}	Collector-Base BreakdownVoltage	$I_{\rm C} = 100 \mu {\rm A}, I_{\rm E} = 0$	60		V
ICEO	Collector Cut-off Current	$V_{CE} = 30V, I_B = 0$		0.1	μA
I _{CBO}	Collector Cut-off Current	$V_{CB} = 30V, I_E = 0$		10	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5.0V, I_B = 0$		10	nA
On Characte	eristics	•			•
h _{FE}	DC Current Gain	$\label{eq:VCE} \begin{array}{l} V_{CE} = 5.0V, \ I_{C} = 10 \mu A \\ V_{CE} = 5.0V, \ I_{C} = 100 \mu A \\ V_{CE} = 5.0V, \ I_{C} = 1.0mA \\ V_{CE} = 5.0V, \ I_{C} = 10mA \end{array}$	250 250 250 250	650	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 10mA, I _B = 0.5mA I _C = 100mA, I _B = 5.0mA		0.2 0.6	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5.0V, I_{C} = 1.0mA$	0.56	0.66	V
Small Signa	I Characteristics				
f _T	Current gain Bandwidth Product	$V_{CE} = 5.0V, I_{C} = 1.0mA,$ f = 100MHz	100	700	MHz
C _{obo}	Output Capacitance	$V_{CB} = 10V, I_E = 0, f = 1.0MHz$		3.0	pF
C _{ibo}	Input Capacitance	V _{EB} = 0.5V, I _C = 0, f = 1.0MHz		8.0	pF

*Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%

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Thermal Characteristics T _A =25°C unless otherwise noted				
Symbol	Parameter	Max.	Units	
P _D	Total Device Dissipation Derate above 25°C	350 2.8	mW mW/°C	
R _{θJC}	Thermal Resistance, Junction to Case		°C/W	
R _{θJC} R _{θJA}	Thermal Resistance, Junction to Ambient	357	°C/W	
evice mounted o	n FR-4 PCB 1.6" X 1.6" X 0.06."			

MMBT6428



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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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